

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

TITLE: **QUANTUM DOT INFRARED PHOTODETECTOR AND
METHOD FOR FABRICATING THE SAME**

INVENTORS: **LIN, SHIH-YEN**

ADDRESS: NO. 149, SHENGLI RD., HSINCHU,
TAIWAN, R.O.C.

CITIZENSHIP: TAIWAN, R.O.C.

TANG, SHIANG-FENG

ADDRESS: NO. 8, LANE 120, WENSHINNAN 3RD RD.,
TAICHUNG, TAIWAN, R.O.C.

CITIZENSHIP: TAIWAN, R.O.C.

LEE, SI-CHEN

ADDRESS: 5 FL., NO. 5, ALLEY 1, LANE 40,
JOUSHAN RD., TAIPEI, TAIWAN, R.O.C.

CITIZENSHIP: TAIWAN, R.O.C.

KUAN, CHIEH-HSIUNG

ADDRESS: 4 FL., NO. 11, LANE 23, SEC. 2,
ANHE RD., TAIPEI, TAIWAN, R.O.C.

CITIZENSHIP: TAIWAN, R.O.C.

ASSIGNEE: **NATIONAL SCIENCE COUNCIL**

18 FL. NO. 106 SEC. 2., HO-PING E. RD,
TAIPEI, TAIWAN, R.O.C.

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